

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	-30	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current (Note 5) V_{GS} = -10V	Steady State	T _A = +25°C T _A = +70°C	ID	-2.5 -2.0	А
Continuous Drain Current (Note 6) V_{GS} = -10V	Steady State	T _A = +25°C T _A = +70°C	Ι _D	-3.8 -3.0	А
Continuous Drain Current (Note 6) V_{GS} = -10V	t ≦10sec	T _A = +25°C T _A = +70°C	ID	-4.6 -3.6	A
Continuous Drain Current (Note 6) V_{GS} = -4.5V	Steady State	T _A = +25°C T _A = +70°C	Ι _D	-3.1 -2.5	А
Pulsed Drain Current (Note 6)			I _{DM}	-20	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	Po	0.76	W
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	159	°C/W
Total Power Dissipation (Note 6)	PD	1.36	W
Thermal Resistance, Junction to Ambient (Note 6)	Reja	94	°C/W
Total Power Dissipation (Note 6) $t \leq 10 \text{sec}$	PD	1.9	W
Thermal Resistance, Junction to Ambient (Note 6) t \leq 10sec	Reja	65.8	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

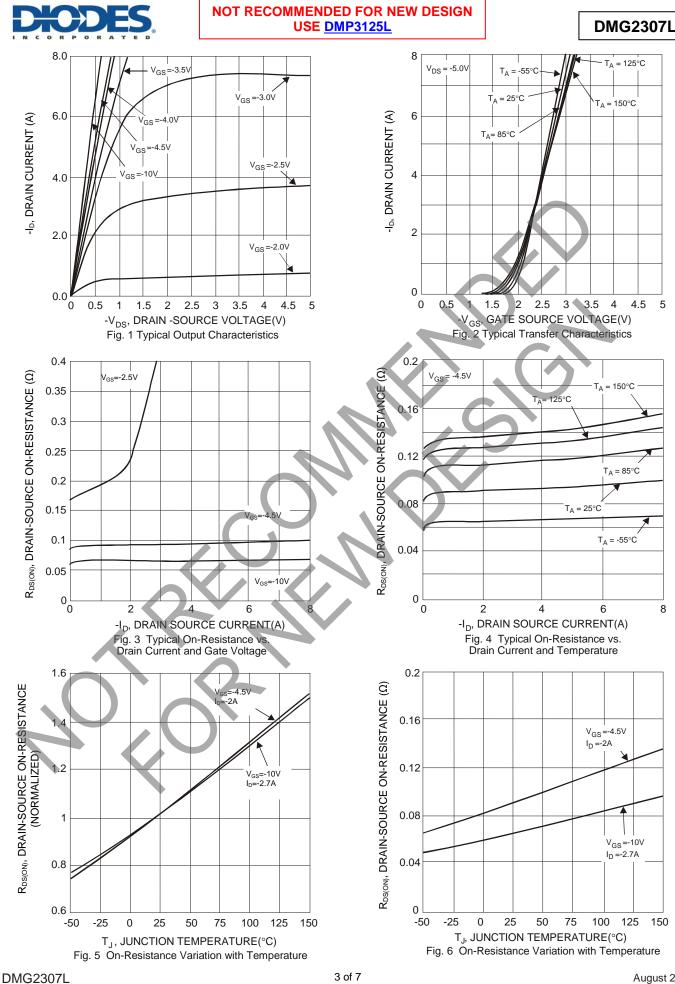
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)		Symbol	INIT.	тур	WIAX	Onit	Test condition	
Drain-Source Breakdown Voltage		BV _{DSS}	-30	_		V	$V_{GS} = 0V, I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current @Tc	= +25°C	IDSS		_	-1.0	μA	$V_{DS} = -30V, V_{GS} = 0V$	
Gate-Source Leakage		Igss	_		±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)								
Gate Threshold Voltage		VGS(TH)	-1.0	_	-3.0	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	
Static Drain-Source On-Resistance		R _{DS(ON)}	_	70	90	mΩ	$V_{GS} = -10V, I_D = -2.5A$	
Static Drain-Source On-Resistance			—	105	134		$V_{GS} = -4.5V, I_D = -2.5A$	
Forward Transfer Admittance		Y _{fs}	—	4.8	_	s	$V_{DS} = -10V, I_{D} = -2.5A$	
Diode Forward Voltage (Note 6)		V_{SD}	—	-0.75	-1.0	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 8)								
Input Capacitance		Ciss	—	371.3	_	pF		
Output Capacitance		Coss	_	51.3	_	pF	V _{DS} = -15V, V _{GS} = 0V, − f = 1.0MHz	
Reverse Transfer Capacitance		Crss	—	45.9		pF		
Gate Resistance		Rg	—	17	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge ($V_{GS} = -4.5V$)		Qg	_	4.0		nC		
Total Gate Charge (V _{GS} = -10V)		Qg	—	8.2		nC	V _{GS} = -10V, V _{DS} = -15V, I _D = -3A	
Gate-Source Charge		Q _{gs}	—	0.9	_	nC		
Gate-Drain Charge		Q _{gd}	—	1.2		nC		
Turn-On Delay Time		t _{D(ON)}		4.8		ns		
Turn-On Rise Time		t _R		7.3		ns	$V_{DS} = -15V, V_{GS} = -10V,$ $R_L = 15\Omega, R_G = 6\Omega,$ $I_D = -1A$	
Turn-Off Delay Time		t _{D(OFF)}	_	22.4		ns		
Turn-Off Fall Time		t _F	—	13.4		ns		

Notes:

Device mounted on FR-4 PCB, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.



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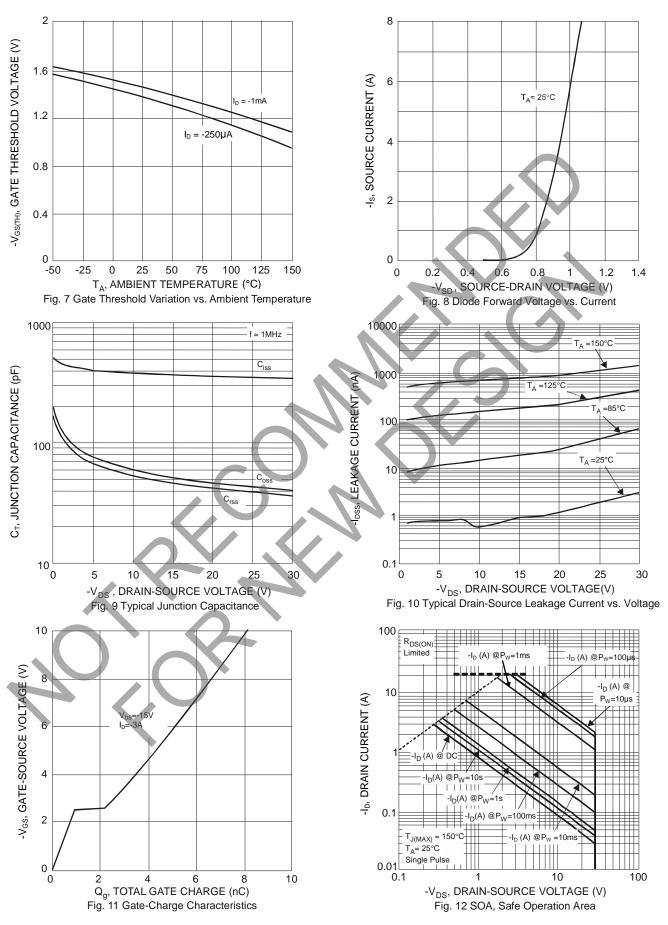
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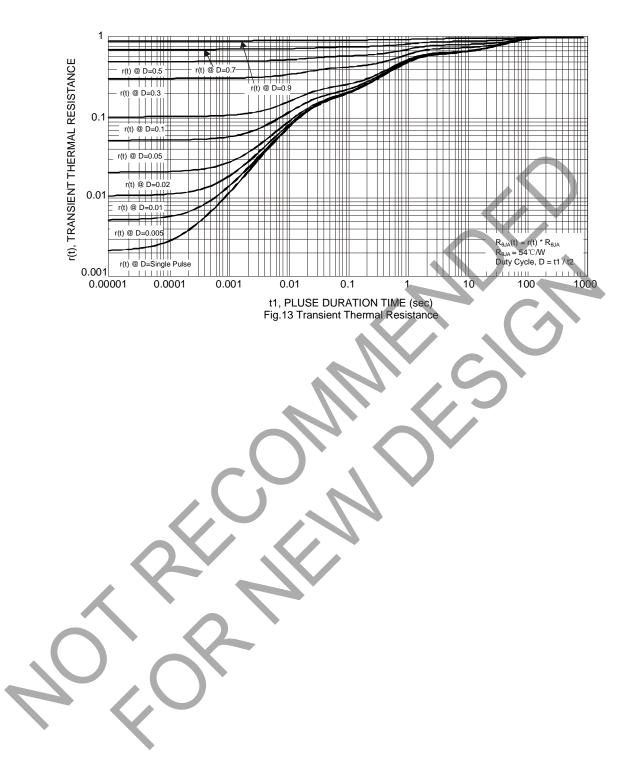


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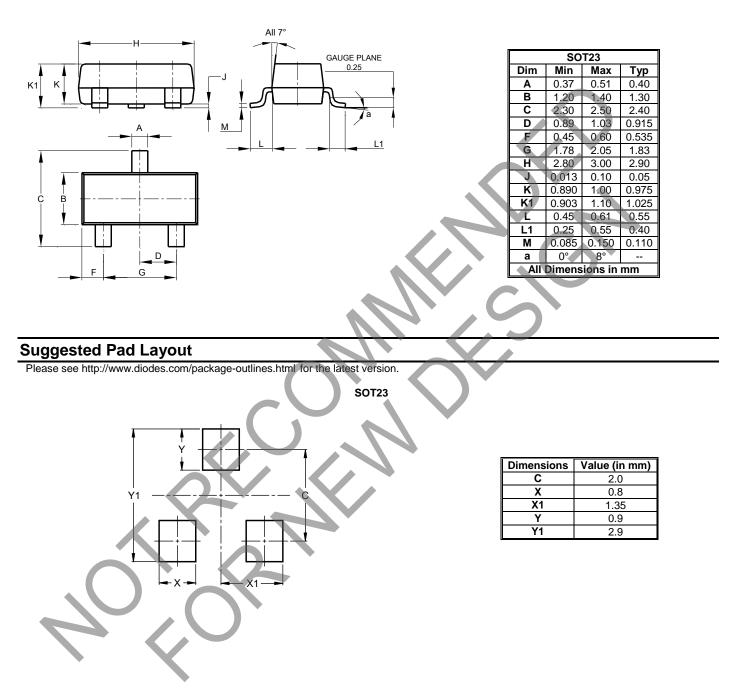




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

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